

ISL6520EVAL1

Embedded DC-DC Converters Using ISL6520 and ISL6520A PWM Controller ICs

AN9932
Rev 0.00
May 2001

Introduction

The ISL6520 and the ISL6520A are voltage mode controllers with many functions that are needed for a multitude of demanding applications. The ISL6520 and ISL6520A contain a high performance error amplifier, a high accuracy reference, a fixed 300kHz internal oscillator and over-current protection circuitry. There are two MOSFET drivers for use in synchronous-rectified Buck converters. The ISL6520A is also capable of regulating the output voltage while the DC-DC converter is sinking current. All these features are packaged in a small 8 pin SOIC. More complete descriptions of the ISL6520 and the ISL6520A can be found in their respective datasheets [1,2].

This application note details the ISL6520 and ISL6520A in DC-DC converters for applications requiring a tightly regulated, fixed output voltage. Any low-cost application requiring a DC-DC converter can benefit from one of the designs presented in this application note

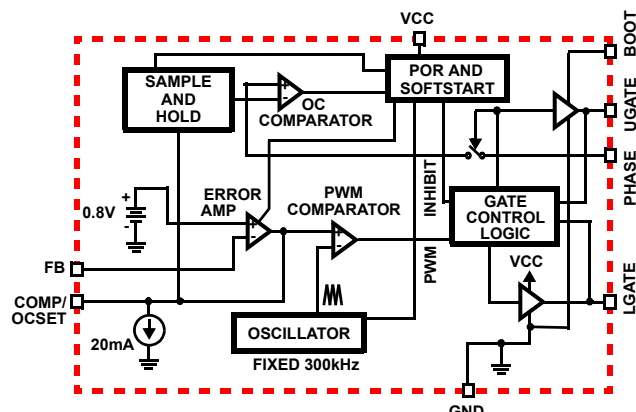


FIGURE 1. ISL6520 BLOCK DIAGRAM

ISL6520 Reference Design

The ISL6520EVAL1 is an evaluation board that highlights the operation of the ISL6520 in an embedded application. The evaluation board is populated with the ISL6520 controller IC, however, the designer may evaluate the ISL6520A simply by removing the ISL6520 IC and replacing it with the ISL6520A. The ISL6520EVAL1 is flexible enough to allow for reference designs with 5A, 10A, and 15A output currents at a fixed output voltage of 3.3V. A simple resistor change allows the output to go as low as 0.8V to as high as the input voltage. This flexibility allows a power supply designer to easily modify an existing design to suit almost any relevant application. The ISL6520EVAL1 DC-DC converter demo boards are customized to provide up to 15A of current at a fixed output voltage. The circuit configurations described in this application note refer to the demo board customized to 15A, unless otherwise noted. The schematic,

Bill of Material, and Board Layout for the ISL6520EVAL1 can be found in the appendix. Customization of the reference design is discussed below.

Quick Start Evaluation

The input to the ISL6520EVAL1 board will only accept 5V from a standard power supply. The outputs can be exercised using either resistive or electronic loads. The shutdown switch, SW1, will allow the designer to evaluate how the ISL6520 shuts down and starts up. Pressing the switch will shut the converter down while releasing it will allow the converter to restart.

Startup

The ISL6520 and the ISL6520A have identical start up sequences. Figure 2 shows a typical start up sequence. Once the input voltage has exceeded the Power On Reset (POR) threshold level, the IC will begin its start up sequence.

First, the error amplifier is disabled allowing 20μA of current to be drawn through a resistor tied between V_{CC} and the COMP/OCSET pin. The voltage that is impressed across the resistor is then read and sampled at the COMP/OCSET pin, with respect to V_{CC}. It is then held in internal memory as the overcurrent set point used in the upper MOSFET R_{DS(on)} overcurrent sensing feature.

After the overcurrent set point is established, the error amplifier is re-enabled and the ISL6520 then initiates its soft start sequence through the use of an internally generated soft start ramp. The entire start up procedure typically takes about 11ms from POR.

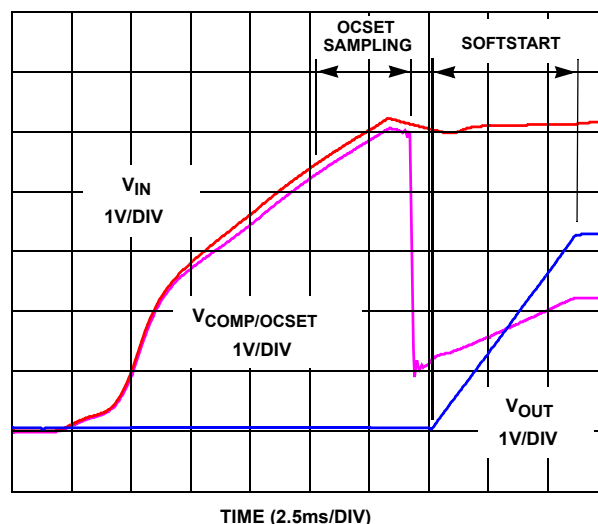


FIGURE 2. SYSTEM STARTUP

Shutdown and Restart

DC-DC converters that utilize the ISL6520 or the ISL6520A may be shut down by pulling the COMP/OSCET pin below 0.8V. One method to implement this feature is to connect the drain of a source grounded small signal MOSFET to the COMP/OSCET pin so that an external signal may trigger the command. The regulator will react to the shutdown command by pulling both of the MOSFET gates to ground, thus shutting down the converter.

The ISL6520EVAL1 board demonstrates the shutdown feature with a push button. Depressing the push button will disable the converter by pulling the COMP/OSCET pin to ground. Once released, the converter will follow its normal start up procedure, which includes the overcurrent set point programming and soft-start.

Reference Design Customization

The ISL6520EVAL1 evaluation board was designed to be as flexible as possible for the power supply designer. The board will accommodate either DPAK or D2PAK packaged MOSFETs in the same footprint and in either the upper or lower MOSFET locations. This allows for a wide range of power levels on the same board. The designer may also implement either a Type II or a Type III compensation network. Finally, there are component locations in place that allow the designer to incorporate output voltage droop into the design.

Table 1 presents reference values for three different converter designs that may be used on the ISL6520EVAL1 board. The reference designs are optimized for 5A, 10A, and 15A maximum output capabilities. For further customization, recommended guidelines for component selection are included below.

Input Capacitor Selection

The number of input capacitors and their capacitances are usually determined by their maximum RMS current ratings. A

conservative approach to determining the number and type of input capacitors is to determine the converter maximum input RMS current and assume it would all be supplied by the input capacitors. This approach works well for converters that employ a filtering inductor on their inputs. In these types of converters, all of the RMS current is supplied by the input capacitors. For converters that do not employ an input inductor, such as the reference design on the ISL6520EVAL1 board, the conservative approach may be too costly. The number of capacitors may be decreased by assuming that only 50% of the RMS current is supplied by the input capacitors. This approach will usually provide enough capacitors to provide proper power decoupling.

The voltage rating at maximum ambient temperature should be 1.25 to 1.5 times the maximum input voltage. More conservative approaches can bring the voltage rating up to 2 times the maximum input voltage. High frequency decoupling, which is highly recommended, is implemented through the use of ceramic capacitors in parallel with the bulk capacitor filtering.

The reference design utilizes Sanyo 330 μ F, 6.3V POSCAP capacitors as the bulk input capacitors (Sanyo Part Number 6TPB330M). Each of these capacitors has a 3A_{RMS} maximum allowable ripple current rating. The number of capacitors used in each design, which is shown in Table 1, is more than sufficient to handle the input RMS current under the assumption that only 50% of that current is being supplied by the input capacitance.

The ISL6520EVAL1 board can accommodate multiple MOSFET package styles. Each placeholder can accommodate DPAK or D2PAK package connections. The output loading and the thermal environment ultimately dictate the MOSFET selected. While many factors are involved in the selection of the MOSFETs, overall efficiency of the regulator should be a major contributor. There are three major aspects of power loss that are associated with the MOSFET. These are gate drive power losses, conduction losses, and switching losses.

TABLE 1. ISL6520EVAL1 DESIGN RECOMMENDATIONS

COMPONENTS	REFERENCE DESIGN	MAXIMUM LOAD CURRENT		
		DESIGN A - 5A	DESIGN B - 10A	DESIGN C - 15A
MOSFETS	Q1, Q2	FAIRCHILD HUF76121D3S	FAIRCHILD HUF76129D3S	FAIRCHILD HUF76143S3S
Inductor	L1	6.4 μ H Panasonic ETQP6F6R4HFA	3.2 μ H Panasonic ETQP6F3R2HFA	2.0 μ H Panasonic ETQP6F2R0LFA
Number of Input Capacitors	C12, C13	1	1	2
Number of Output Capacitors	C8, C9, C10	1	2	3
Number of Decoupling Capacitors	C5A, C5B	1	1	2
OCSET Resistor	R5	9.06k Ω	12.7k Ω	6.34k Ω

Gate Drive Power Losses result in the power dissipated within the gate drivers, which are located in the ISL6520 and ISL6520A. This power loss is a result of displacing the charge on the gate-to-source capacitance, C_{gs} .

The gate power is frequency dependent and is determined by the equation:

$$P_{gate} = (Q_{gu} \times V_{gu} + Q_{gl} \times V_{gl}) \times f_s$$

where

Q_{gu} = Upper MOSFET gate charge

V_{gu} = Upper MOSFET gate voltage

Q_{gl} = Lower MOSFET gate charge

V_{gl} = Lower MOSFET gate voltage

Conduction Losses are simply I^2R losses. Conduction losses can be approximated as:

$$P_{condu} = R_{dsu} \times D \times I_{LOAD}^2$$

$$P_{condl} = R_{dsl} \times (1 - D) \times I_{LOAD}^2$$

where

P_{condu} = Upper MOSFET Conduction Loss

P_{condl} = Lower MOSFET Conduction Loss

R_{dsu} = Upper MOSFET $R_{DS(on)}$

R_{dsl} = Lower MOSFET $R_{DS(on)}$

D = Duty Cycle

I_{load} = Load Current

Note that the $R_{ds(on)}$ will increase as the junction temperature of the MOSFET increases. This increase in impedance should be taken into account when calculating the conduction losses.

Switching losses are caused by crossover conduction during the switching interval and by the output capacitance, C_{oss} , being displaced. Since the dissipation caused by the output capacitance is very small compared to the loss due to crossover conduction, it can be ignored.

The ISL6520A can introduce switching losses that the ISL6520 will not. Since the ISL6520A gives the converter the ability to sink current, the lower MOSFET will experience switching losses when the converter is in a current sinking state. Since the ISL6520A can switch fluidly from a current sourcing state to a current sinking state and back again, it is prudent to assume a worst case condition of full time current sourcing and sinking when sizing the upper and lower MOSFETs, respectively. The equations shown below give a simplified, yet useful, representation of switching loss for a MOSFET

$$P_{switch} = \frac{1}{2} \times V_{in} \times I_{in} \times t_{sw} \times f_s$$

where

V_{in} = Input Voltage

I_{in} = Input Current

t_{sw} = MOSFET switching time

f_s = Switching Frequency

ISL6520EVAL1 Efficiency

Figure 3 shows the efficiency of the ISL6520EVAL1 for all three design recommendations: 5A maximum load, 10A maximum load, and 15A maximum load respectively. As can be seen in the efficiency curves, the MOSFETs and other components were selected so as to keep a high efficiency throughout the load range of the converter.

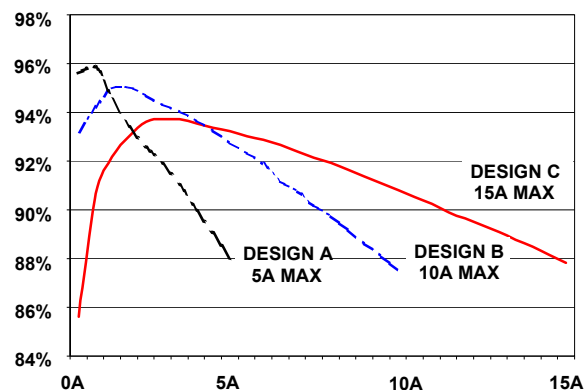


FIGURE 3. ISL6520EVAL1 EFFICIENCY

Output Voltage Programming

Simple resistor value changes allow for outputs as low as 0.8V or as high as the input voltage. The steady state DC output voltage can be set using the following formula:

$$V_{out} = V_{ref} \times \left(1 + \frac{R1}{R4}\right)$$

where

V_{out} = Desired output voltage of converter

V_{ref} = ISL6520 internal reference (0.8V)

The output voltage of the reference designs presented in this application note is 3.3V.

Lossless Output Voltage Droop with Load

The ISL6520EVAL1 board has unpopulated component footprints in place to implement output voltage droop. Droop is an intentional sag in the output voltage that is proportional to the output current. Although not necessary for proper circuit operation, utilizing droop allows the dynamic regulation to be improved by taking advantage of static regulation requirements and expanding the available headroom for transient edge output excursions. In practical applications that are compared to a non-droop implementation, the droop implementation

requires fewer output capacitors or better regulation with the same type and number of output capacitors.

By moving the regulation point ahead of the output inductor (at the PHASE node), droop becomes equal to the average voltage drop across the output inductor's DC resistance as well as any distributed resistance. The droop circuitry is simply an RC low pass filter placed across the output inductor. This filter must have the same time constant that the output inductor and its corresponding DCR have. The design must be careful to include any parasitic impedances of the PC board if the DCR of the inductor is very low.

On the ISL6520EVAL1 board, this filter is represented by resistors R6 and R7 and capacitor C7. Resistor R7 can be used to scale the magnitude of the droop. The output of this low pass filter is fed directly into the feedback compensation network of the regulator. The effects of this filter on the frequency response of the converter is minimal and can be ignored when evaluating the frequency response of the converter. To insure symmetric output voltage excursions about the set voltage in response to load transients, the output voltage should be programmed to be above the nominal level by half the calculated droop.

As supplied, the ISL6520EVAL1 does not employ droop. A successful droop implementation has been designed and tested for Design C. The DCR of the output inductor is 5mΩ. This gives a time constant of:

$$\tau = \frac{L_{out}}{DCR + R_{parasitic}} = 400\mu S \quad \text{with } R_{parasitic} = 0\Omega$$

The impedance portion of the time constant calculation for the RC filter includes the parallel combination of the filter resistor, R6, and the feedback resistor, R1. A value for R6 is chosen that will not significantly decrease the impedance already set by R1. A 16.2kΩ resistor was chosen. This yields an effective impedance of 2.64kΩ. The filter capacitor, C7, is then calculated:

$$\tau = R \times C = 2644 \times C = 400\mu S$$

$$C \sim 0.1\mu F$$

Since the regulation point is now located at the phase node, and a 16.2kΩ resistor is being added to the DC path for regulation, then the resistor, R4, used to program the output voltage must be adjusted. The maximum output current for Design C is 15A and the DCR of the inductor is 5mΩ. This combination will yield a total droop of 75mV. In order to center the droop symmetrically about the 3.3V set point, the no load set point will be 3.375V. The corresponding value for R4 to accomplish this is 6.04kΩ.

Figure 4 shows the output voltage of the converter with the droop circuitry added.

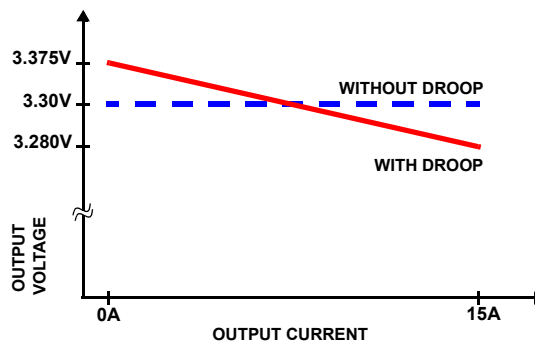


FIGURE 4. OUTPUT VOLTAGE DROOP

Component Values for Droop Implementation:

R6 = 16.2kΩ

R7 = Not Populated

C7 = 0.1μF

R4 = 6.04kΩ

With the proper selection of the components used in the RC filter across the inductor, the frequency response of the system is only minimally affected and the compensation network does not need to be recalculated.

Output Capacitor Selection

The shape of the output voltage waveform during a load transient that represents the worst case loading conditions will ultimately determine the number of output capacitors and their type. When this load transient is applied to the converter, most of the energy required by the load is initially delivered from the output capacitors. This is due to the finite amount of time required for the inductor current to slew up to the level of the output current required by the load. This phenomenon results in a temporary dip in the output voltage. At the very edge of the transient, the Equivalent Series Inductance (ESL) of each capacitor induces a spike that adds on top of the existing voltage drop due to the Equivalent Series Resistance (ESR)

After the initial spike, attributable to the ESR and ESL of the capacitors, the output voltage experiences sag. This sag is a direct consequence of the amount of capacitance on the output.

During the removal of the same output load, the energy stored in the inductor is dumped into the output capacitors. This energy dumping creates a temporary hump in the output voltage. This hump, as with the sag, can be attributed to the total amount of capacitance on the output.

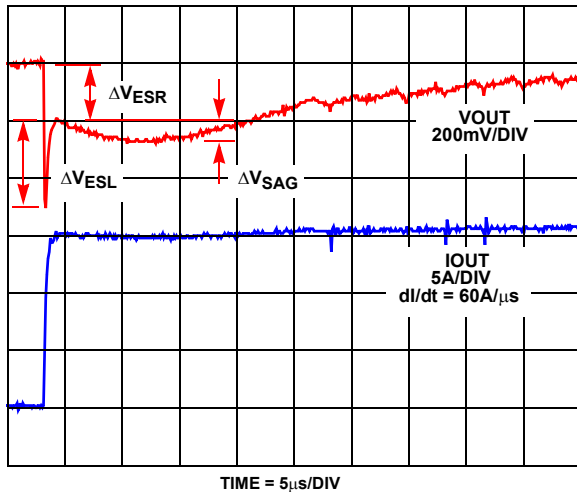


FIGURE 5. TRANSIENT RESPONSE

Figure 5 shows a typical response of the ISL6520EVAL1 to a load transient. The current slew rate was made large to show the effects of the parasitic inductances in the output stage.

The amplitudes of the different types of voltage excursions can be approximated by using the following formulae

$$\Delta V_{ESR} = ESR \times I_{tran} \quad \Delta V_{ESL} = ESL \times \frac{dI_{tran}}{dt}$$

$$\Delta V_{SAG} = \frac{L_{out} \times I_{tran}^2}{C_{out} \times (V_{in} - V_{out})}$$

$$\Delta V_{HUMP} = \frac{L_{out} \times I_{tran}^2}{C_{out} \times V_{out}}$$

where

I_{tran} = Output Load Current Transient

C_{out} = Total Output Capacitance

In a typical converter design, the ESR of the output capacitor bank dominates the transient response. The ESR and the ESL are typically the major contributing factors in determining the output capacitance. The number of output capacitors can be determined by using the following equation that relates the ESR and ESL of the capacitors to the transient load step and the voltage limit (ΔV_o):

$$\text{Number of Caps} = \frac{\frac{ESL \times \Delta I_{tran}}{dt} + ESR \times I_{tran}}{\Delta V_o}$$

If ΔV_{sag} and/or ΔV_{hump} are found to be too large for the output voltage limits, then the amount of capacitance may need to be increased. In this situation, a trade off between output inductance and output capacitance may be necessary.

The ESL of the capacitors, which is an important parameter in the above equations, is not usually listed in databooks.

Practically, it can be approximated if an Impedance Vs. Frequency curve is given for a specific capacitor:

$$ESL = \frac{1}{C} \times (2 \times \pi \times f_{res})^2$$

where f_{res} is the frequency where the lowest impedance is achieved (resonant frequency).

The ESL of the capacitors becomes a concern when designing circuits that supply power to loads with high rates of change in the current.

Output Voltage Ripple

The amount of ripple voltage on the output of the DC-DC converter varies with the input voltage, switching frequency, output inductor, and output capacitors. For a fixed switching frequency and output filter, the voltage ripple increases with the input voltage. The ripple content of the output voltage can be estimated with the following equation:

$$\Delta V_{out} = \Delta I_L \times ESR$$

where

$$\Delta I_L = \frac{(V_{in} - V_{out}) \times \frac{V_{out}}{V_{in}}}{L_{out} \times f_s}$$

If the output capacitors have already been selected to meet certain transient requirements, then the ripple voltage can be set by the output inductance.

Figure 6 shows the output ripple for Design C.

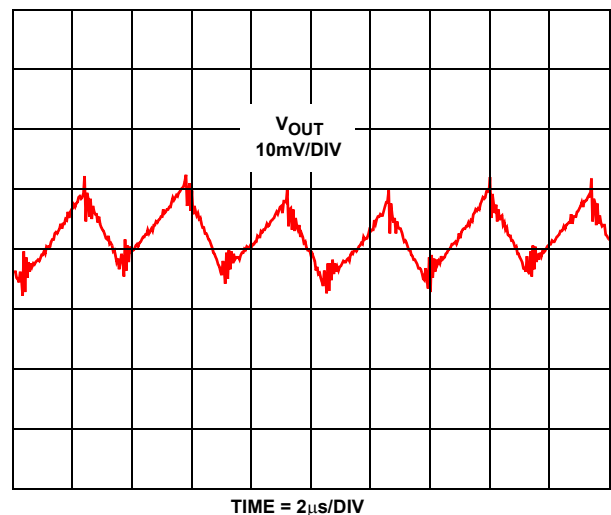


FIGURE 6. OUTPUT VOLTAGE RIPPLE

Conclusion

The ISL6520EVAL1 board is a DC-DC converter reference design that is flexible enough to accommodate a wide range of output current requirements. The printed circuit board is laid out to accommodate the necessary components for operation from low load levels to 15A of output current.

References

For Intersil documents available on the web, see
www.intersil.com/

[1] *ISL6520 Data Sheet*, Intersil Corporation, Doc. # 9009

[2] *ISL6520A Data Sheet*, Intersil Corporation, Doc. # 9016

ISL6520EVAL1 Schematic

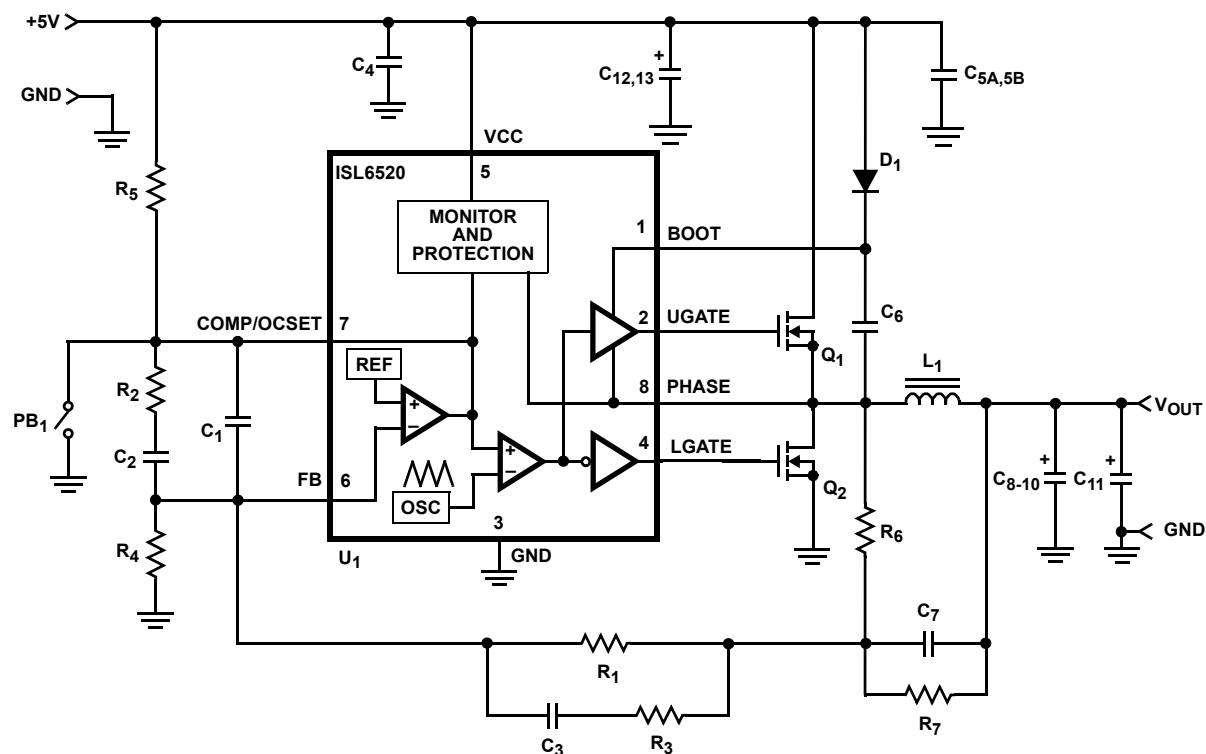
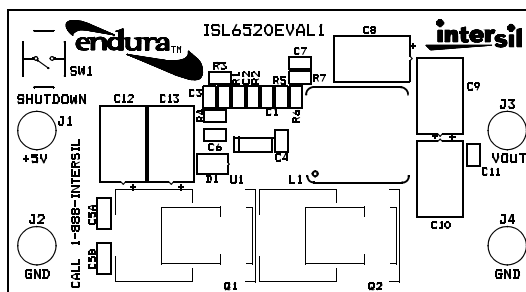


TABLE 2. ISL6520EVAL1 BILL OF MATERIAL

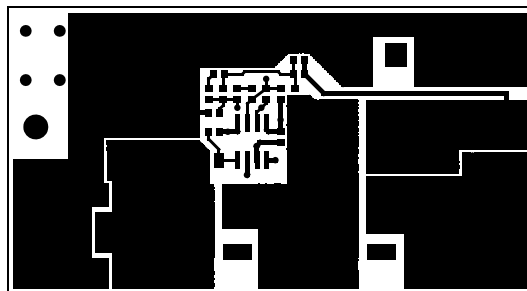
REF DES	DESCRIPTION	VENDOR	VENDOR P/N	QTY
C1	470pF Capacitor, 0603	Various	---	1
C2	8200pF Capacitor, 0603	Various	---	1
C3	18000pF Capacitor, 0603	Various	---	1
C4,C6,C11	0.1μF Capacitor, 0603	Various	---	2
C5A,C5B	1μF Capacitor, 0805	Various	---	2
C7	Not Populated Capacitor, 0603	---	---	---
C8-10, C12, C13	330μF Capacitor	Sanyo	6TPB330M	5
D1	Diode, 30mA, 30V	Digikey	MA732	1
L1	2μH Inductor	Panasonic	ETQP6F2ROLFH	1
Q1, Q2	MOSFET	Fairchild	HUF76143S3S	2
R1	3.16kΩ 1% Resistor, 0603	Various	---	1
R2	10.0kΩ 1% Resistor, 0603	Various	---	1
R3	60.4Ω 1% Resistor, 0603	Various	---	1
R4	1.00kΩ Resistor, 0603	Various	---	1
R5	6.34kΩ Resistor, 0603	Various	---	1
R6	Not Populated Resistor, 0603	---	---	---
R7	0Ω Resistor, 0603	Various	---	1
PB1	Pushbutton, miniature	Digikey	P8007S-ND	1
U1	Single Synchronous Buck PWM Controller	Intersil	ISL6520CB	1
TP1,2,3,4	Test Points	Keystone	1514-2	4

Board Description

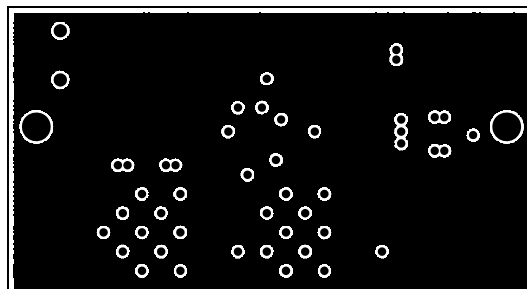
Silk Screen



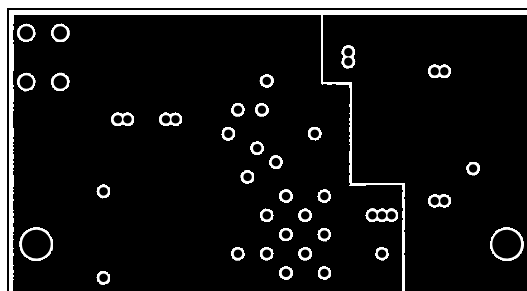
Top Layer



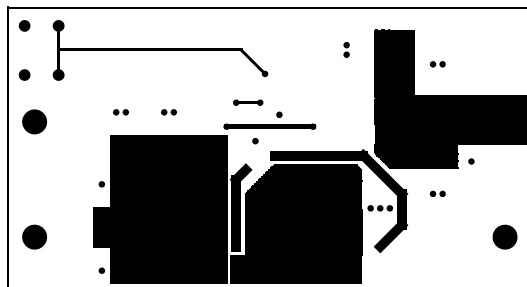
Ground Layer



Power Layer



Bottom Layer



Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
 2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
 3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
 4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.

"Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.

"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.

Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
 6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
 7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
 8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
 9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
 10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
 11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.4.0-1 November 2017)



SALES OFFICES

Renesas Electronics Corporation

<http://www.renesas.com>

Refer to "<http://www.renesas.com/>" for the latest and detailed information.

Renesas Electronics America Inc.
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.
Tel: +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3
Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-6688, Fax: +852-2886-9022

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
Tel: +886-2-8175-9600, Fax: +886-2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India
Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd.
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5338